

Vishay General Semiconductor

Surface Mount Fast Switching Rectifier

Major Ratings and Characteristics

I _{F(AV)}	1.5 A
V _{RRM}	50 V to 800 V
I _{FSM}	50 A
t _{rr}	150 ns, 250 ns, 500 ns
V _F	1.3 V
T _j max.	150 °C



DO-214AA (SMB)

Features

- Low profile package
- Ideal for automated placement
- Glass passivated chip junction
- Fast switching for high efficiency
- High forward surge capability
- Meets MSL level 1, per J-STD-020C
- Solder Dip 260 °C, 40 seconds

Typical Applications

For use in fast switching rectification of power supply, inverters, converters, and freewheeling diodes for consumer, automotive and Telecommunication

Maximum Ratings

	•	
(T _Δ = 25 °C	unless otherwise noted)	1

$(1_A = 25$ °C unless otherwise noted)								
Parameters	Symbols	RS2A	RS2B	RS2D	RS2G	RS2J	RS2K	Units
Device marking code		RA	RB	RD	RG	RJ	RK	
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	500	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	V
Maximum average forward rectified current at $T_L = 100\ ^\circ C$	I _{F(AV)}	1.5						Α
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	50						A
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150						°C



Mechanical Data

Case: DO-214AA (SMB) Epoxy meets UL-94V-0 Flammability rating Terminals: Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D E3 suffix for commercial grade, HE3 suffix for high reliability grade (AEC Q101 qualified) Polarity: Color band denotes cathode end

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RS2A thru RS2K

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Electrical Characteristics

(T_A = 25 °C unless otherwise noted)

Parameters	Test condition	Symbols	RS2A	RS2B	RS2D	RS2G	RS2J	RS2K	Units
Maximum instantaneous forward voltage	at 1.5 A	V _F	1.3						
Maximum DC reverse current at rated DC blocking voltage	T _A = 25 °C T _A = 125 °C	I _R	5.0 200						
Maximum reverse recovery time	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A	t _{rr}		1	50		250	500	ns
Typical junction capacitance	at 4.0 V, 1 MHz	CJ	20 17					pF	

Thermal Characteristics

(T_A = 25 °C unless otherwise noted)

Parameters	Symbols	RS2A	RS2B	RS2D	RS2G	RS2J	RS2K	Units
Typical thermal resistance ⁽¹⁾	R _{θJA} R _{θJL}	55 18				°C/W		

Notes:

(1) Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.27×0.27 " (7.0 x 7.0 mm) copper pad

Ratings and Characteristics Curves

 $(T_A = 25 \degree C \text{ unless otherwise noted})$



Figure 1. Forward Current Derating Curve



Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



RS2A thru RS2K

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Figure 4. Typical Reverse Characteristics

Package outline dimensions in inches (millimeters)



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Figure 5. Typical Junction Capacitance



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